



N-Channel Depletion-Mode Vertical DMOS FETs

Features

- ▶ High input impedance
- ▶ Low input capacitance
- ▶ Fast switching speeds
- ▶ Low on-resistance
- ▶ Free from secondary breakdown
- ▶ Low input and output leakage

Applications

- ▶ Normally-on switches
- ▶ Solid state relays
- ▶ Converters
- ▶ Linear amplifiers
- ▶ Constant current sources
- ▶ Power supply circuits
- ▶ Telecom

General Description

This low threshold depletion-mode (normally-on) transistor utilizes an advanced vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and with the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Ordering Information

Device	Package Option	BV _{DSX} /BV _{DGX} (V)	R _{DS(ON)} (max) (Ω)	I _{DSS} (min) (mA)
	TO-243AA (SOT-89)			
DN3535	DN3535N8-G	350	10	200

-G indicates package is RoHS compliant ('Green')



Absolute Maximum Ratings

Parameter	Value
Drain-to-source voltage	BV _{DSX}
Drain-to-gate voltage	BV _{DGX}
Gate-to-source voltage	±20V
Operating and storage temperature	-55°C to +150°C
Soldering temperature*	300°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

* Distance of 1.6mm from case for 10 seconds.

Pin Configuration



TO-243AA (SOT-89)

Product Marking

DN5SW W = Code for week sealed
 _____ = "Green" Packaging
TO-243AA (SOT-89)

Thermal Characteristics

Package	I_D (continuous) [†] (mA)	I_D (pulsed) (mA)	Power Dissipation @ $T_A = 25^\circ\text{C}$ (W)	θ_{jc} ($^\circ\text{C}/\text{W}$)	θ_{ja} ($^\circ\text{C}/\text{W}$)	I_{DR}^\ddagger (mA)	I_{DRM} (mA)
TO-243AA	230	500	1.6 [‡]	15	78 [†]	230	500

Notes:

- [†] I_D (continuous) is limited by max rated T_r
- [‡] Mounted on FR4 board, 25mm x 25mm x 1.57mm.

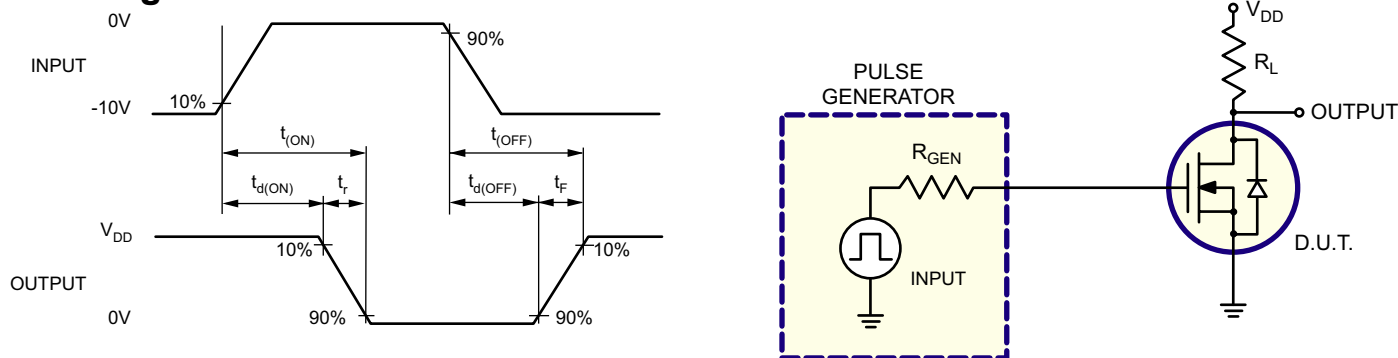
Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Sym	Parameter	Min	Typ	Max	Units	Conditions
BV_{DSS}	Drain-to-source breakdown voltage	350	-	-	V	$V_{GS} = -5.0\text{V}, I_D = 1.0\mu\text{A}$
$V_{GS(OFF)}$	Gate-to-source off voltage	-1.5	-	-3.5	V	$V_{DS} = 15\text{V}, I_D = 10\mu\text{A}$
$\Delta V_{GS(OFF)}$	Change in $V_{GS(OFF)}$ with temperature	-	-	-4.5	mV/ $^\circ\text{C}$	$V_{DS} = 15\text{V}, I_D = 10\mu\text{A}$
I_{GSS}	Gate body leakage current	-	-	100	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
$I_{D(OFF)}$	Drain-to-source leakage current	-	-	1.0	μA	$V_{DS} = \text{Max rating}, V_{GS} = -5.0\text{V}$
		-	-	1.0	mA	$V_{DS} = 0.8 \text{ Max Rating}, V_{GS} = -5.0\text{V}, T_A = 125^\circ\text{C}$
I_{DSS}	Saturated drain-to-source current	200	-	-	mA	$V_{GS} = 0\text{V}, V_{DS} = 15\text{V}$
$R_{DS(ON)}$	Static drain-to-source on-state resistance	-	-	10	Ω	$V_{GS} = 0\text{V}, I_D = 150\text{mA}$
$\Delta R_{DS(ON)}$	Change in $R_{DS(ON)}$ with temperature	-	-	1.1	%/ $^\circ\text{C}$	$V_{GS} = 0\text{V}, I_D = 150\text{mA}$
G_{FS}	Forward transconductance	200	-	-	mmho	$V_{DS} = 10\text{V}, I_D = 100\text{mA}$
C_{ISS}	Input capacitance	-	-	360	pF	$V_{GS} = -5.0\text{V}, V_{DS} = 25\text{V}, f = 1.0\text{MHz}$
C_{OSS}	Common source output capacitance	-	-	40		
C_{RSS}	Reverse transfer capacitance	-	-	10		
$t_{d(ON)}$	Turn-on delay time	-	-	15	ns	$V_{DD} = 25\text{V}, I_D = 150\text{mA}, R_{GEN} = 25\Omega, V_{GS} = 0\text{V to } -10\text{V}$
t_r	Rise time	-	-	20		
$t_{d(OFF)}$	Turn-off delay time	-	-	20		
t_f	Fall time	-	-	30		
V_{SD}	Diode forward voltage drop	-	-	1.8	V	$V_{GS} = -5.0\text{V}, I_{SD} = 150\text{mA}$
t_{rr}	Reverse recovery time	-	800	-	ns	$V_{GS} = -5.0\text{V}, I_{SD} = 150\text{mA}$

Notes:

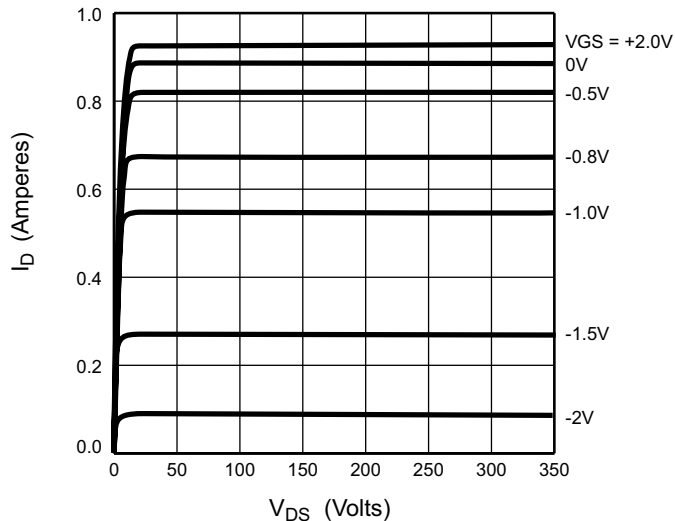
- All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300 μs pulse, 2% duty cycle.)
- All A.C. parameters sample tested.

Switching Waveforms and Test Circuit

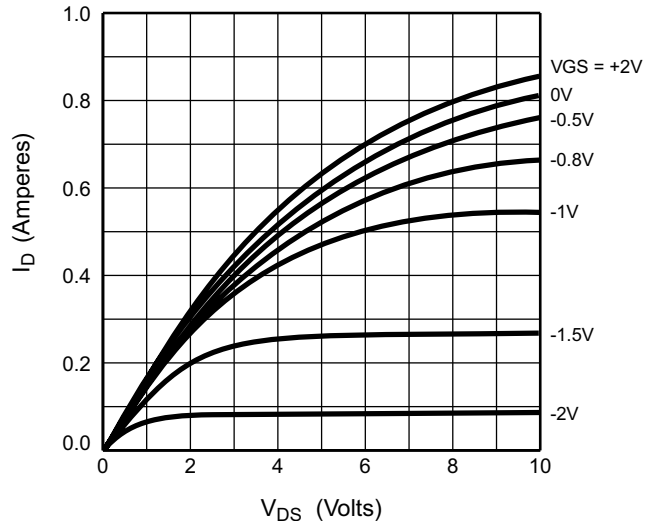


Typical Performance Curves

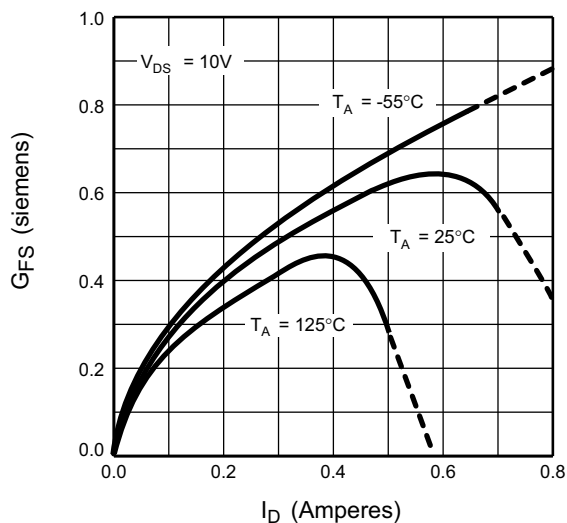
Output Characteristics



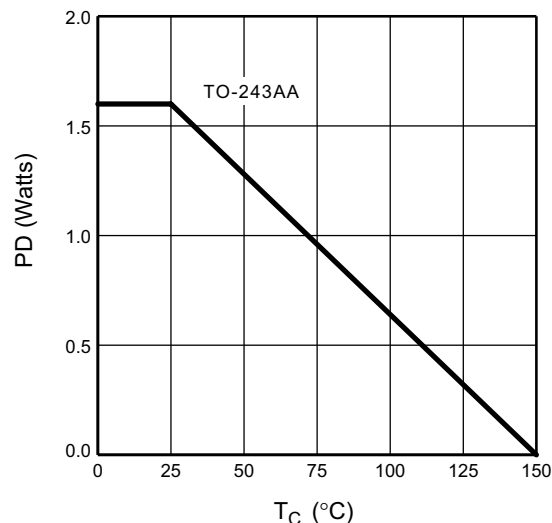
Saturation Characteristics



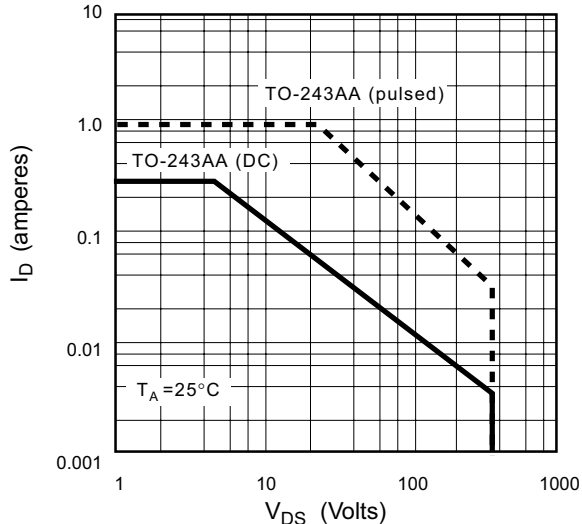
Transconductance vs. Drain Current



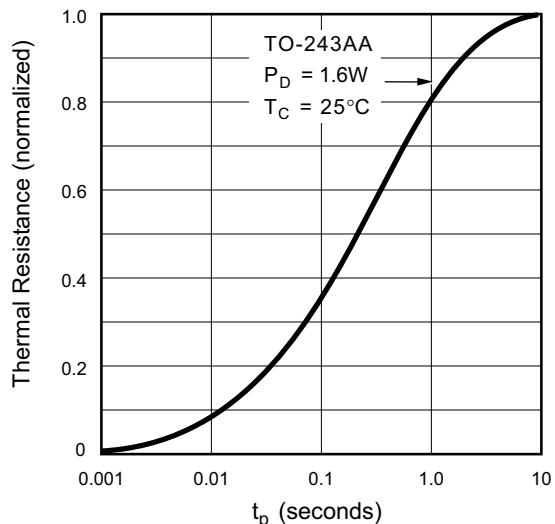
Power Dissipation vs. Case Temperature



Maximum Rated Safe Operating Area

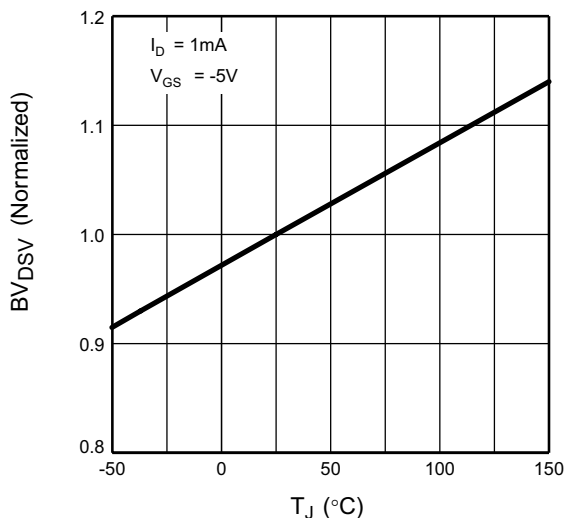


Thermal Response Characteristics

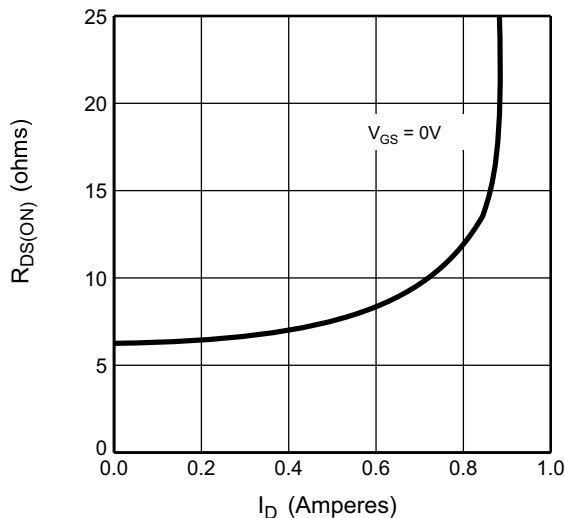


Typical Performance Curves (cont.)

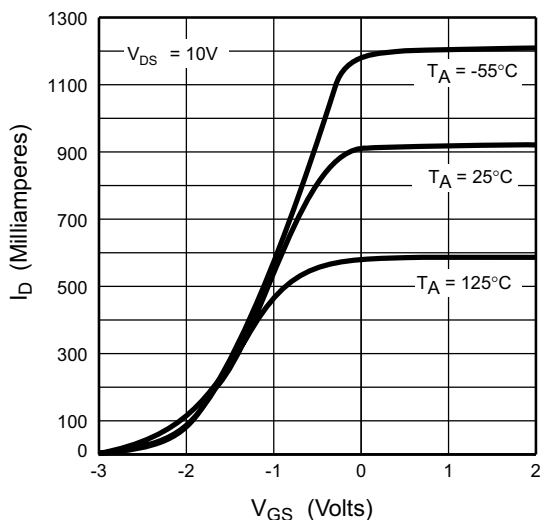
BV_{DSV} Variation with Temperature



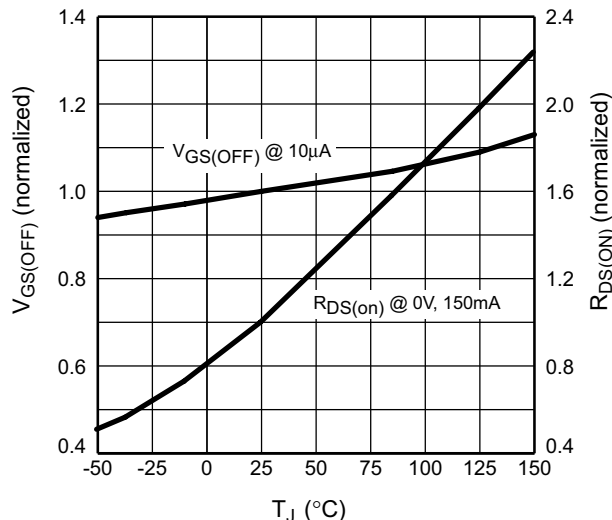
On Resistance vs. Drain Current



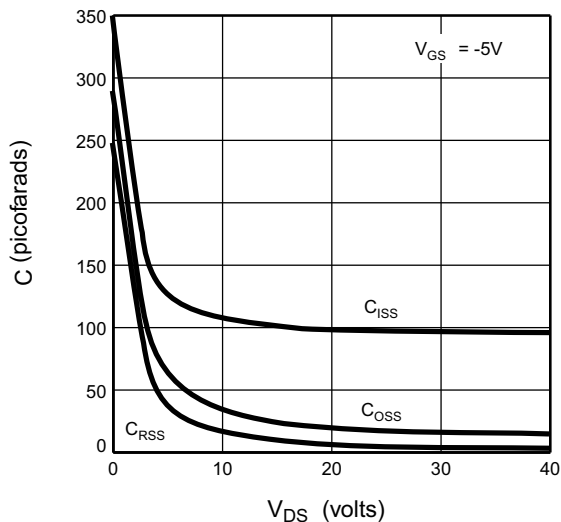
Transfer Characteristics



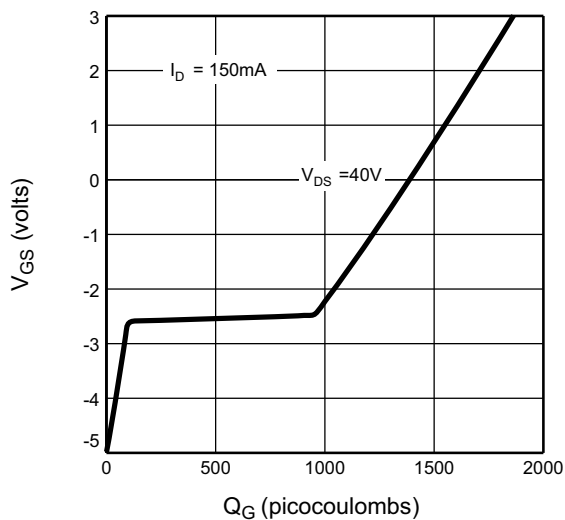
V_{GS(OFF)} and R_{DS(ON)} w/ Temperature



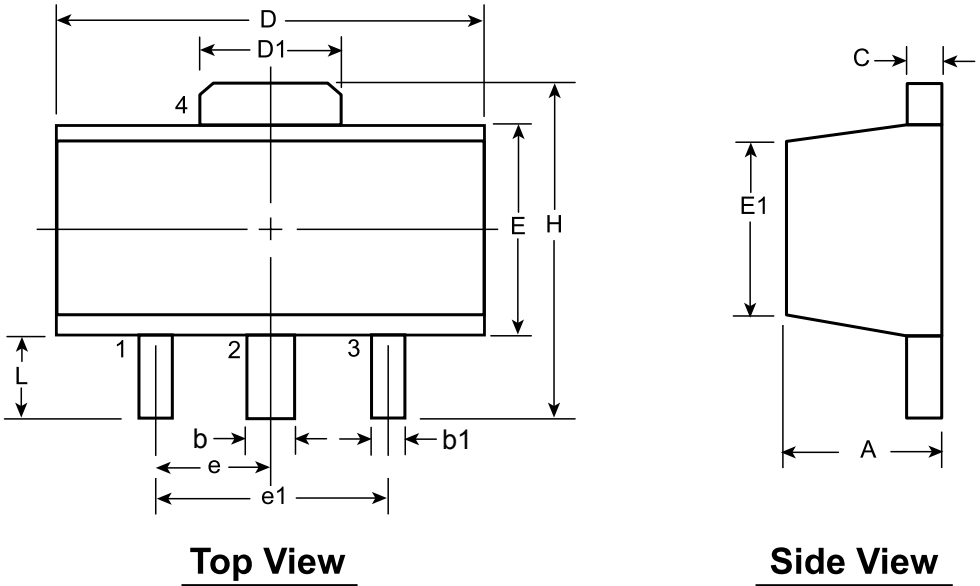
Capacitance vs. Drain Source Voltage



Gate Drive Dynamic Characteristics



3-Lead TO-243AA (SOT-89) Package Outline (N8)



Top View

Side View

Symbol		A	b	b1	C	D	D1	E	E1	e	e1	H	L
Dimensions (mm)	MIN	1.40	0.44	0.36	0.35	4.40	1.62	2.29	2.13	1.50 BSC	3.00 BSC	3.94	0.89
	NOM	-	-	-	-	-	-	-	-			-	-
	MAX	1.60	0.56	0.48	0.44	4.60	1.83	2.60	2.29			4.25	1.20

JEDEC Registration TO-243, Variation AA, Issue C, July 1986.

Drawings not to scale.

Supertex Doc. #: DSPD-3TO243AAN8, Version D070908.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <http://www.supertex.com/packaging.html>.)

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